

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSo)

On-resistance: $R_{DS(ON)} = 90 \text{ m}\Omega$ (typ.)

Low leakage current: $I_{DSS} = 10 \text{ }\mu\text{A}$ (max) ($V_{DS} = 100 \text{ V}$)

Enhancement-model: $V_{th} = 2.0$ to 4.0 V ($V_{DS} = 10 \text{ V}$, $I_D = 1.0 \text{ mA}$)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	100	V
Gate-source voltage		V_{GSS}	± 20	V
Drain current	DC (Note 1)	I_D	8	A
	Pulse (Note 1)	I_{DP}	16	
Drain power dissipation ($T_c = 25^\circ\text{C}$)		P_D	18	W
Single pulse avalanche energy (Note 2)		E_{AS}	4	mJ
Avalanche current		I_{AR}	8	A
Channel temperature		T_{ch}	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$

Note : Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

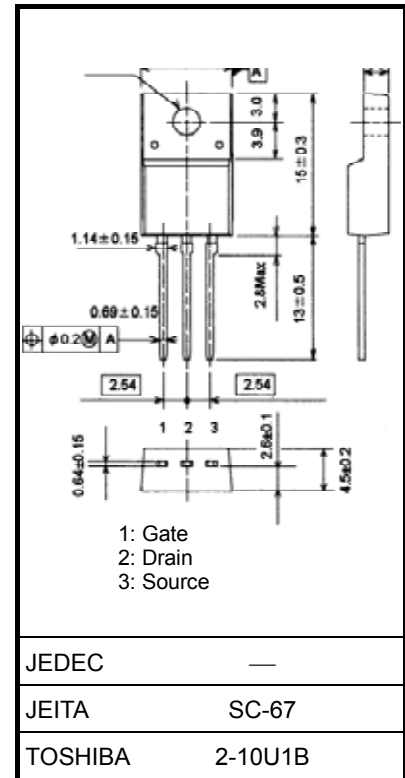
Note 1: Please use devices on condition that the channel temperature is below 150°C .

Note 2: $V_{DD} = 25 \text{ V}$, $T_{ch} = 25^\circ\text{C}$, $L = 100 \text{ }\mu\text{H}$, $R_G = 25 \text{ }\Omega$, $I_{AR} = 8 \text{ A}$

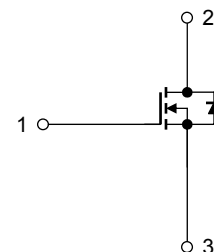
Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th(ch-c)}$	6.94	$^\circ\text{C} / \text{W}$
Thermal resistance, channel to ambient	$R_{th(ch-a)}$	62.5	$^\circ\text{C} / \text{W}$

This transistor is an electrostatic sensitive device. Please handle with caution.



Weight: 1.7 g (typ.)



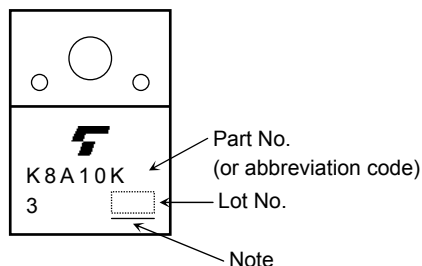
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 100	nA
Drain cut-OFF current		I_{DSS}	$V_{DS} = 100\text{ V}, V_{GS} = 0\text{ V}$	—	—	10	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	100	—	—	V
		$V_{(BR)DSX}$	$I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$	65	—	—	
Gate threshold voltage		V_{th}	$V_{DS} = 10\text{ V}, I_D = 1.0\text{ mA}$	2.0	—	4.0	V
Drain-source ON resistance		$R_{DS(ON)}$	$V_{GS} = 10\text{ V}, I_D = 4\text{ A}$	—	90	120	m Ω
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 4\text{ A}$	3.6	7.2	—	S
Input capacitance		C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	530	—	pF
Reverse transfer capacitance		C_{rss}		—	55	—	
Output capacitance		C_{oss}		—	75	—	
Switching time	Rise time	t_r		—	15	—	ns
	Turn-ON time	t_{on}		—	25	—	
	Fall time	t_f		—	5.4	—	
	Turn-OFF time	t_{off}		—	27	—	
Total gate charge (gate-source plus gate-drain)		Q_g	$V_{DD} \approx 80\text{ V}, V_{GS} = 10\text{ V}, I_D = 8\text{ A}$	—	12.9	—	nC
Gate-source charge		Q_{gs1}		—	5.4	—	
Gate-drain ("miller") charge		Q_{gd}		—	6.4	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

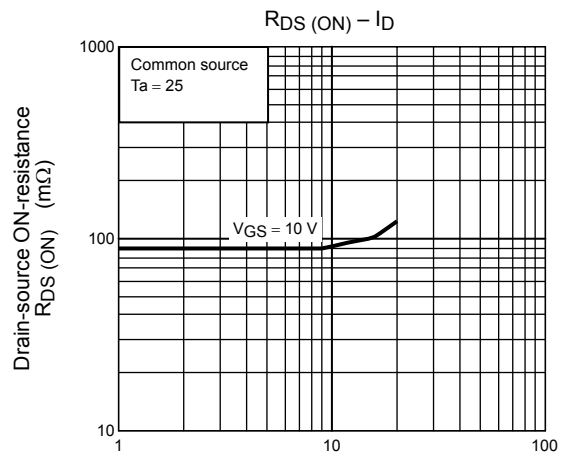
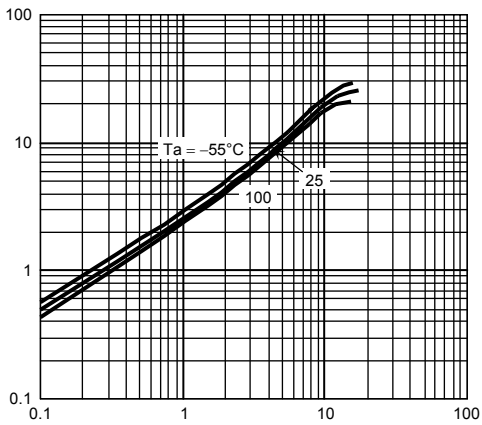
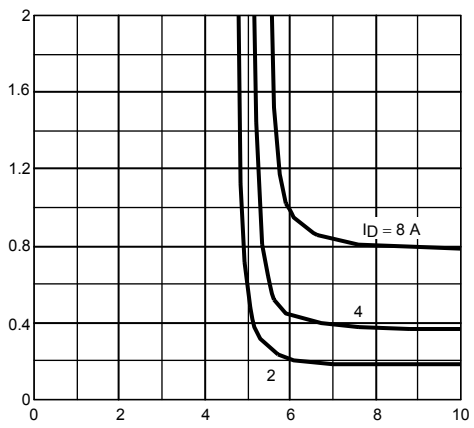
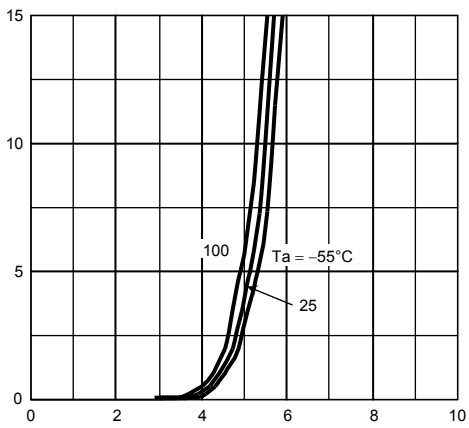
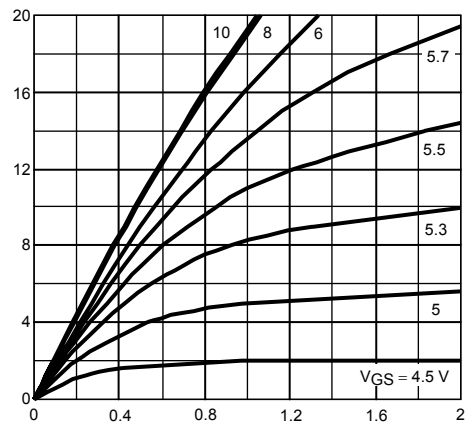
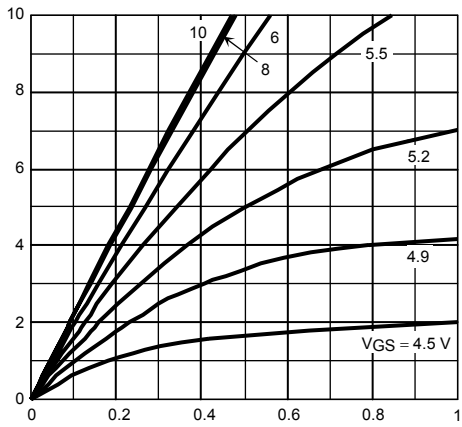
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	—	—	—	8	A
Pulse drain reverse current (Note 1)	I_{DRP}	—	—	—	16	A
Forward voltage (diode)	V_{DSF}	$I_{DR} = 8\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.4	V
Reverse recovery time	t_{rr}	$I_{DR} = 8\text{ A}, V_{GS} = 0\text{ V},$	—	50	—	ns
Reverse recovery charge	Q_{rr}	$dI_{DR}/dt = 50\text{ A}/\mu\text{s}$	—	50	—	nC

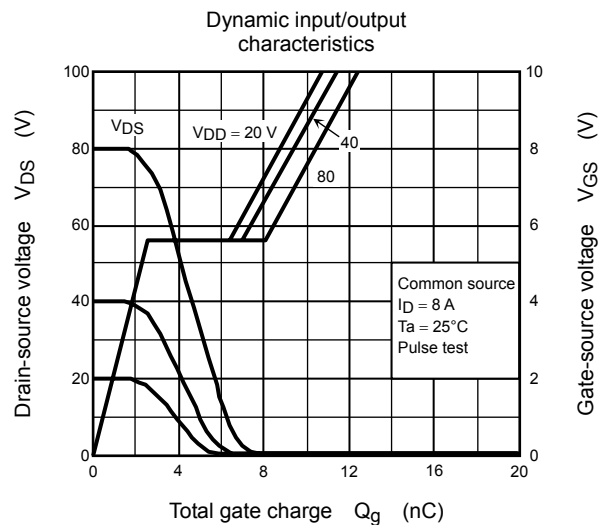
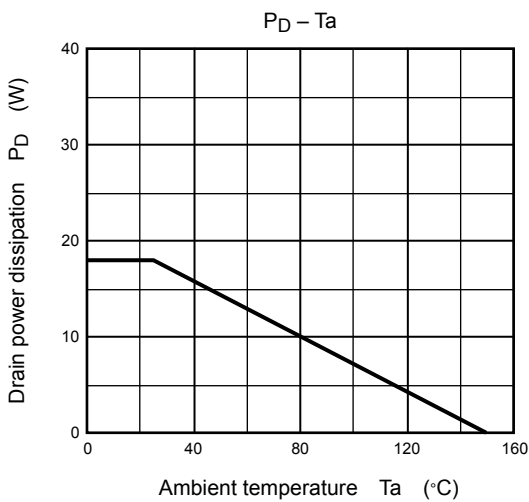
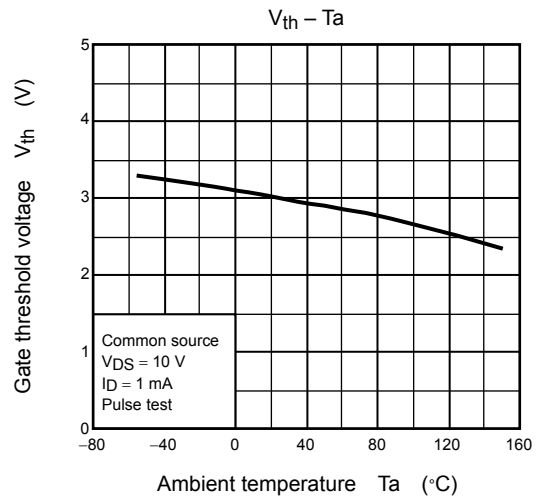
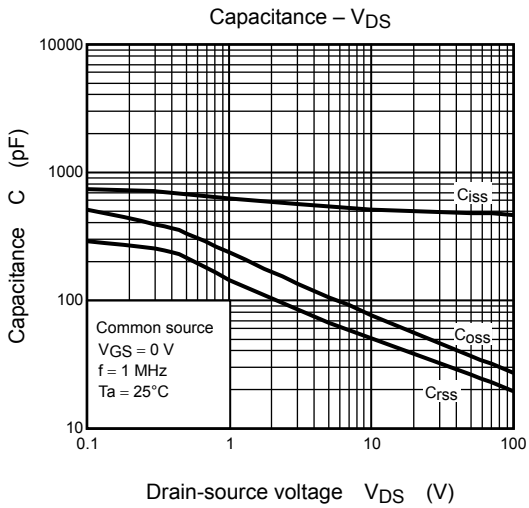
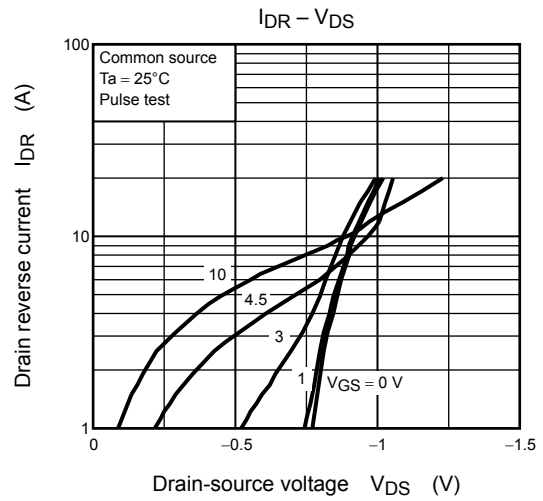
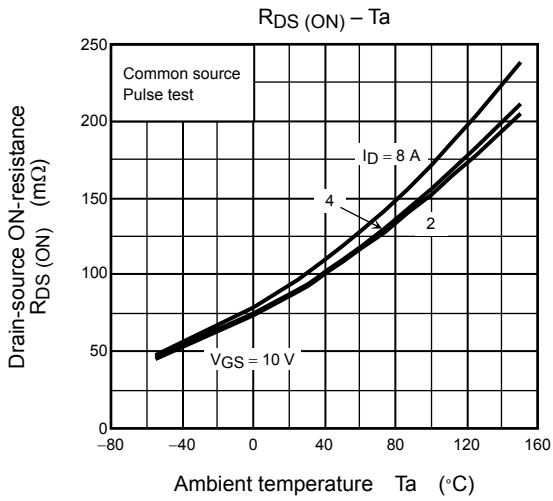
Marking

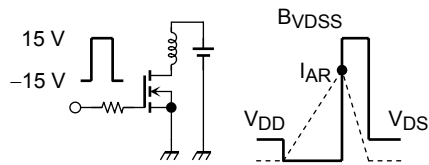
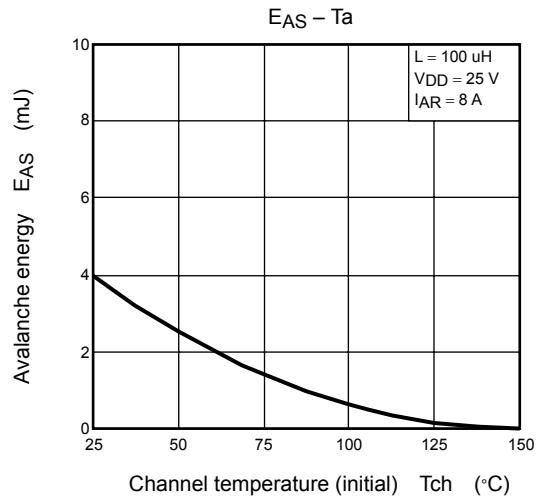
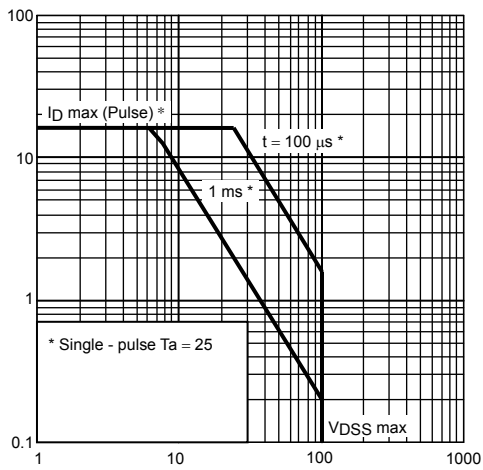
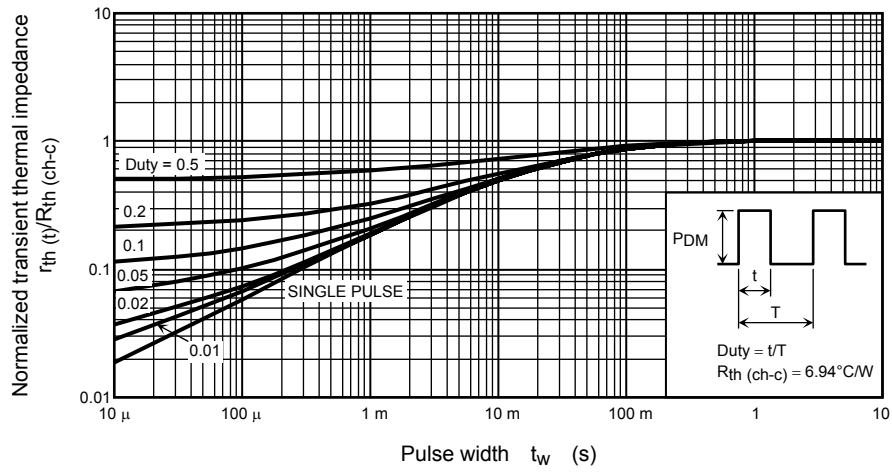


Note : A line under a Lot No. identifies the indication of product Labels
[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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